

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Diodes Division</u> <u>SS32-E3/57T</u>

For any questions, you can email us directly: sales@integrated-circuit.com



www.vishay.com

SS32, SS33, SS34, SS35, SS36

Vishay General Semiconductor

Surface Mount Schottky Barrier Rectifier



DO-214AB (SMC)

PRIMARY CHARACTERISTICS						
I _{F(AV)} 3.0 A						
V_{RRM}	20 V, 30 V, 40 V, 50 V, 60 V					
I _{FSM}	100 A					
EAS	20 mJ					
V _F	0.5 V, 0.75 V					
T _J max.	150 °C					
Package	DO-214AB (SMC)					
Diode variations	Single					

FEATURES

- Low profile package
- · Ideal for automated placement
- Guardring for overvoltage protection
- · Low power losses, high efficiency
- Low forward voltage drop
- High surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

MECHANICAL DATA

Case: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	SS32	SS33	SS34	SS35	SS36	UNIT
Device marking code		S2	S3	S4	S5	S6	
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	V
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	V
Maximum average forward rectified current at T _L (fig. 1)	I _{F(AV)}	3.0				Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	100				А	
Non-repetitive avalanche energy at T_A = 25 °C, I_{AS} = 2.0 A, L = 10 mH	E _{AS}	20				mJ	
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs		
Operating junction temperature range	TJ	-55 to +150			°C		
Storage temperature range	T _{STG}	-55 to +150				°C	

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of SS32-E3/57T - DIODE SCHOTTKY 20V 3A DO214AB

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.vishay.com

SS32, SS33, SS34, SS35, SS36

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
PARAMETER	TEST C	ONDITIONS	SYMBOL	SS32	SS33	SS34	SS35	SS36	UNIT
Maximum instantaneous forward voltage (1)	3.0 A		V _F		0.5		0.	75	V
Maximum DC reverse current		T _A = 25 °C	i	0.5			mA		
at rated DC blocking voltage (1)		T _A = 100 °C	IR		20		1	0	IIIA

Note

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL SS32 SS33 SS34 SS35 SS36 UNI				UNIT		
Typical thermal resistance (1)	$R_{\theta JA}$	55					°C/W
Typical trieffial resistance (*)	$R_{\theta JL}$	17					C/VV

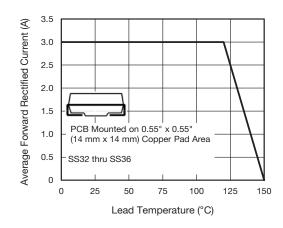
Note

(1) PCB. mounted 0.55" x 0.55" (14 mm x 14 mm) copper pad areas

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
SS34-E3/57T	0.235	57T	850	7" diameter plastic tape and reel				
SS34-E3/9AT	0.235	9AT	3500	13" diameter plastic tape and reel				
SS34HE3_A/H (1)	0.235	Н	850	7" diameter plastic tape and reel				
SS34HE3_A/I (1)	0.235	I	3500	13" diameter plastic tape and reel				

Note

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





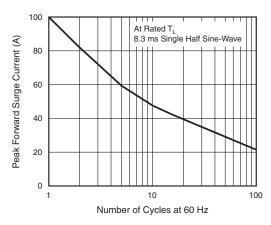


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

⁽¹⁾ AEC-Q101 qualified

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of SS32-E3/57T - DIODE SCHOTTKY 20V 3A DO214AB

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



SS32, SS33, SS34, SS35, SS36

Vishay General Semiconductor

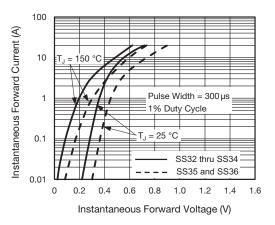


Fig. 3 - Typical Instantaneous Forward Characteristics

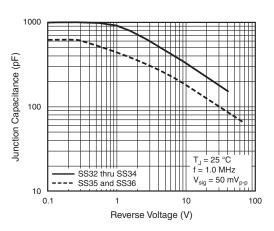


Fig. 5 - Typical Junction Capacitance

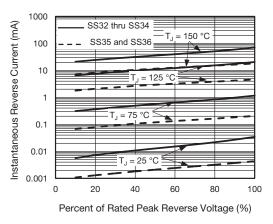


Fig. 4 - Typical Reverse Current Characteristics

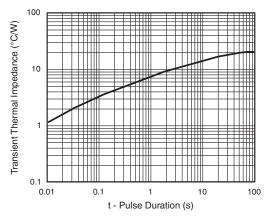
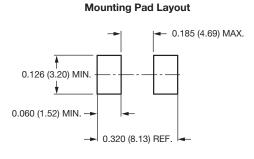


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AB (SMC) Cathode Band 0.246 (6.22) 0.126 (3.20) 0.220 (5.59) 0.114 (2.90) 0.280 (7.11) 0.260 (6.60) 0.012 (0.305) 0.006 (0.152) 0.103 (2.62) 0.079 (2.06) 0.060 (1.52) 0.008 (0.2) 0.030 (0.76) 0 (0) 0.320 (8.13) 0.305 (7.75)



Revision: 04-Aug-15 3 Document Number: 88751



Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of SS32-E3/57T - DIODE SCHOTTKY 20V 3A DO214AB Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.vishay.com

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 13-Jun-16 1 Document Number: 91000